## NSN 5961-01-080-4549

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-080-4549

view Offilite at https://defobasegroup.com/his//0301-01-000-4043
Inclosure Material:
Metal
Overall Length:
1.573 inches
Terminal Length:
0.440 inches
Overall Height:
0.328 inches
Overall Width:
1.050 inches
End Application:
F-16a&b usaf
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
450.0 collector-to-emitter, substaining voltage, base open-circuited and 450.0 collector to base voltage/static/emitter open and 5.0 emitted
to base voltage, static, collector open
Current Rating Per Characteristic:
Between 1.00 amperes source cutoff current and 10.00 amperes source cutoff current
Power Rating Per Characteristic:
125.0 watts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Leads plated gold
Test Data Document:
08748-tr49 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:

N/a

2 pin and 1 case
Shelf Life:

## NSN 5961-01-080-4549

Transistor - Page 2 of 2



		• •			
ш	ın	10	<i>(</i> )+	Measure:	

--

Demilitarization:

No

Fiig:

A110a0